

COMPLETE THIS FORM TO INITIATE SUPPLIER SCOUTING

MEPNN Supplier Scouting Opportunity Synopsis

- □ *The submitting entity agrees to notify NIST MEP of the status of actions taken as a result of this scouting instance within 30 days after receiving a results report. For instances where the submitting entity is an MEP Center submitting on behalf of a client, the MEP Center agrees to notify NIST MEP on behalf of their client. For instances where the submission is direct from federal/state agencies or is a private company, the submitting federal/state agency or private company entity agrees to notify NIST MEP. Notification should be via email to scouting@nist.gov, indicating the following:
 - Contact with matches identified in report complete and supply contract awarded, process complete
 - Contact with matches identified in report complete and no supply contract awarded, process complete
 - Contact with matches identified in report complete and supply negotiations underway, process in progress
 - Contact with matches identified in report underway; supply negotiations not yet begun; process in progress
 - Contact with matches identified in report not yet begun, process in progress
 - Contact with matches identified in report will not occur within the next 6-months, process complete

Inductively Coupled Plasma Reactive Ion Etcher	

Opportunities will be postedfor 30 days unless specified

Item to be Scouted

Please describe the item application/ the end use of item.* Provide the item number if applicable: (N95 Mask vs Protective Mask).

The National Institute of Standards and Technology (NIST) seeks information on commercial vendors that can provide an Inductively Coupled Plasma (ICP) reactive ion etcher for etching metal, silicon, and III-V compounds to support nanofabrication in the Center for Nanoscale Science and Technology (CNST) user facility. The system will be sited and used as a shared resource accessible to researchers from industry, academia, NIST, and other government agencies in the CNST NanoFab. This ICP etching system is a pattern transfer tool that uses chlorine compounds and other chemicals to fabricate micron- and nano-scale structures in metals, metal oxides, silicon, III-V compounds, and other substrates. Applications include fabricating nano-semiconductor and nano-photonic devices

2022-126	
Supplier Scouting Number (NIST MEP use)	
333242	

Scouting customer/product NAICS Code, if known						
⊒	1. Supplier Information	a. Type of supplier being sought*				
TECHNICAL INFORMATION:		■ Manufacturer □ Contract Manufacturer □ Distributor				
		□ Other				
Ä		b. Reason for scouting submission*				
ξ		☐ 2 nd Supplier ☐ Price ☐ Re-shore ☐ Past supplier no longer available				
≨		☐ New Product Startup				
Ę	š	■ Other				
N.						
	2. Summary of Tand Performanc	a. Describe the manufacturing processes (elaborate to provide as much detail as possible).*				
		Item needed as one standalone unit				
	y of man	b. Provide dimensions / size / tolerances / performance specifications for the item.*				
	of Technic nce Requ	. General Description As described above, this ICP system is a pattern transfer tool that uses an inductively coupled plasma to fabricate micronand nano-scale structures in metals, silicon, and III-V compounds, primarily using chlorine and other etching gases. This new ICP will be used to minimize the system down time, improve the process repeatability and add new NanoFab's etching process capabilities. 2. Tool configuration: The system must be equipped with following components: 1) A load-lock that transfers the samples in and out of the process chamber. 2) A process				

chamber that is compatible with reactive chemicals such as chlorine (Cl2), boron trichloride (BCl3) and other gases. 3) A process chamber that is capable to handle 12 different gases. 4) An ICP source that operates from 0 to 3000 W. 5) A RIE electrode that operates from 0 to 500 W or higher. 6) A pumping system that is compatible with chlorine-based chemistries and maintains a base pressure of 9x10-7 Torr or lower. 7) Software that supports both manual and automatic operations. 8) Safety interlocks to keep users safe. 3. Wafer compatibility and temperature: 1) The system shall be able to process substrates with various sizes including 75 mm, 100 mm, 150 mm and 200 mm substrate. 2) The system shall be able to process substrates from -150 °C to +400 °C. 3) The system shall have mechanical wafer clamping and backside helium cooling. 2. Established process library: 1) The system shall have established processes for etching Al, Al2O3, Cr, Cr2O3. Mo, Ti, Si, InP, GaAs, GaN and other materials. 2) Established process documentation shall include process parameters such as etch rate, selectivity, and profile with scanning electron microscope



c. List required materials	needed to make the product, inclu	ding materials of product components.
Item needed as one st	andalone unit.	



	2.	d. Are there applicable certification requirements?* Yes No Please explain
	Sumr	
	nary	
	of Te	e. Are there applicable regulations?* Yes No
	chnic	Please explain
	Summary of Technical Specifications cont:	
		f. Are there any other standards, requirements, etc.?* Yes No
	s and	Please explain
	Perfo	
	and Performance Requirements	g. Additional Comments: Is there other information that would impact the item's performance or usefulness? Please explain.
	ice R	userumess: Please explain.
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BUSINESS INFORMATION	3. Volume and Pricing	3a. Estimated potential business volume (i.e., # Units Per Day, Month, Year) *:
		One unit
SS IN	e and	
FOR		b. Estimated target price / unit cost information (flexible and negotiable not accepted) *:
MATI		\$700,000.00
ON:	4. D	a. When is it needed by? (Immediate, 30 Days, 6 months, etc.)*
	eliver	ASAP b. Describe packaging requirements (i.e., individually/group packaging)*
	y Re	
	Delivery Requirements:	Flexible
	ment	c. Where will this item be shipped?*
	s:	NIST, 100 Bureau Drive, Gaithersburg, MD 20899
	(7)	Is there other information you would like to include?
	5. Ad	is there other information you would like to include:
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	Additional Comments:	
	ents:	